

# PC716V

## High Sensitivity, High Output Type Photocoupler

\* Lead forming type (I type) and taping reel type (P type) are also available. (PC716VI/PC716VP)

\*\* TÜV (VDE0884) approved type is also available as an option.

### ■ Features

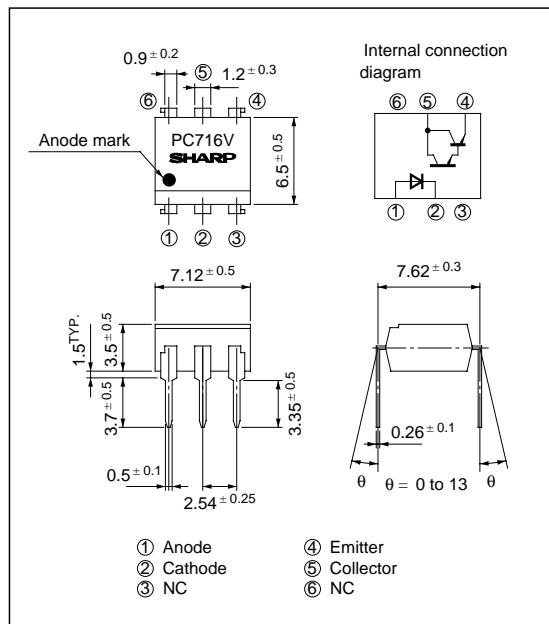
1. High current transfer ratio  
(CTR : MIN. 1 000% at  $I_F = 1\text{mA}$ ,  $V_{CE} = 2\text{V}$ )
2. High collector power dissipation  
( $P_c : 300\text{mW}$ )
3. High isolation voltage between input and output  
( $V_{iso} : 5\,000\text{V}_{rms}$ )
4. Recognized by UL, file No. E64380

### ■ Applications

1. DC-DC SSRs
2. Power monitors, welding machines
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

### ■ Outline Dimensions

(Unit : mm)



### ■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	$I_F$	50	mA
	* <sup>1</sup> Peak forward current	$I_{FM}$	1	A
	Reverse voltage	$V_R$	6	V
	Power dissipation	$P$	70	mW
Output	Collector-emitter voltage	$V_{CEO}$	35	V
	Emitter-collector voltage	$V_{ECO}$	6	V
	Collector current	$I_C$	200	mA
	Collector power dissipation	$P_c$	300	mW
	Total power dissipation	$P_{tot}$	350	mW
	* <sup>2</sup> Isolation voltage	$V_{iso}$	5 000	$\text{V}_{rms}$
	Operating temperature	$T_{opr}$	- 25 to + 100	°C
	Storage temperature	$T_{stg}$	- 40 to + 125	°C
	* <sup>3</sup> Soldering temperature	$T_{sol}$	260	°C

\*1 Pulse width <= 100 μs, Duty ratio : 0.001

\*2 40 to 60% RH, AC for 1 minute

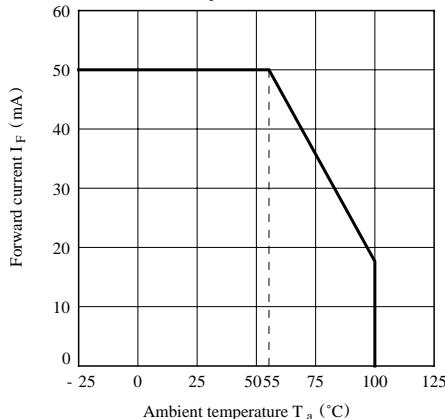
\*3 For 10 seconds

## ■ Electro-optical Characteristics

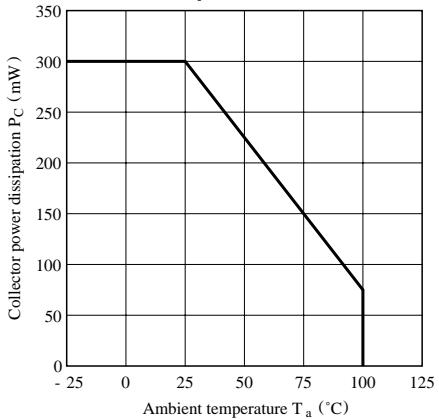
(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10mA	-	1.2	1.4	V
	Peak forward voltage	V <sub>FM</sub>	I <sub>FM</sub> = 0.5A	-	-	3.0	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 4V	-	-	10	μA
	Terminal capacitance	C <sub>t</sub>	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> = 10V, I <sub>F</sub> = 0	-	-	10 <sup>-6</sup>	A
Transfer characteristics	Current transfer ratio	CTR	I <sub>F</sub> = 1mA, V <sub>CE</sub> = 2V	1 000	6 000	15 000	%
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> = 20mA, I <sub>C</sub> = 10mA	-	-	1.2	V
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60% RH	5 × 10 <sup>10</sup>	10 <sup>11</sup>	-	Ω
	Floating capacitance	C <sub>f</sub>	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency	f <sub>c</sub>	V <sub>CE</sub> = 2V, I <sub>C</sub> = 10mA, R <sub>L</sub> = 100Ω, -3dB	-	3	-	kHz
	Response time	tr	V <sub>CE</sub> = 2V, I <sub>C</sub> = 20mA, R <sub>L</sub> = 100Ω	-	130	400	μs
		t <sub>f</sub>		-	60	350	μs

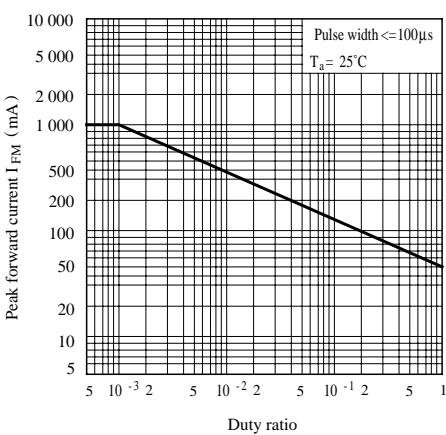
**Fig. 1 Forward Current vs. Ambient Temperature**



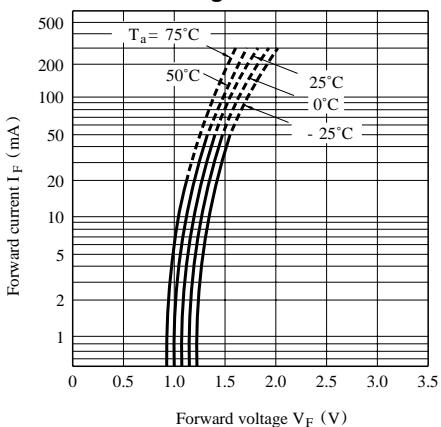
**Fig. 2 Collector Power Dissipation vs. Ambient Temperature**



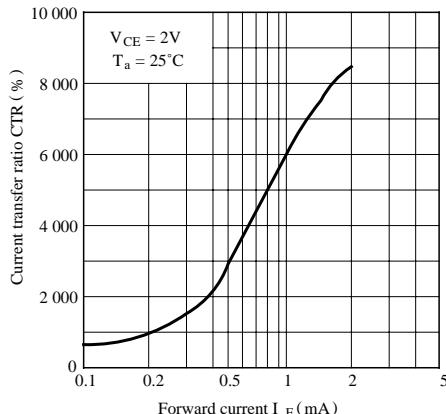
**Fig. 3 Peak Forward Current vs. Duty Ratio**



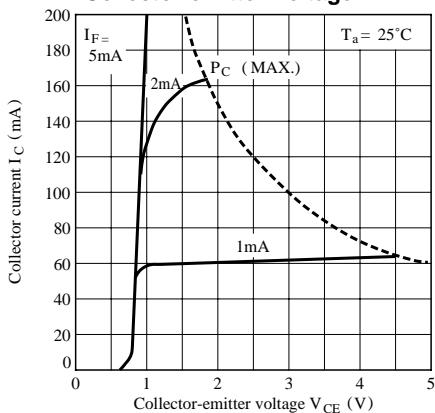
**Fig. 4 Forward Current vs. Forward Voltage**



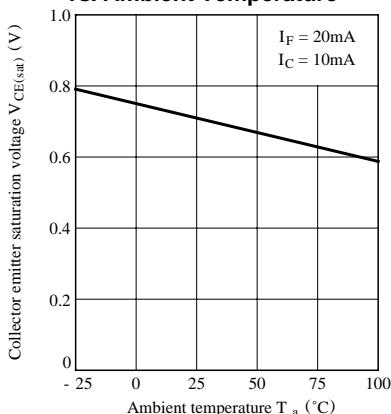
**Fig. 5 Current Transfer Ratio vs. Forward Current**



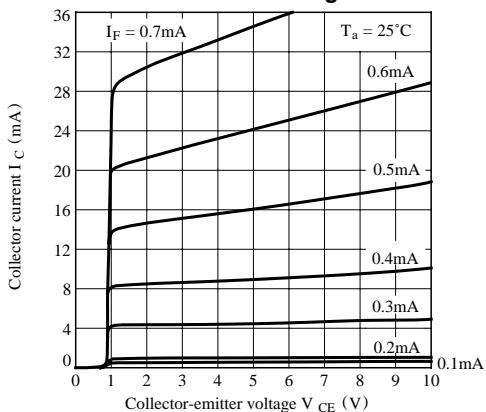
**Fig. 6-b Collector Current vs. Collector-emitter Voltage**



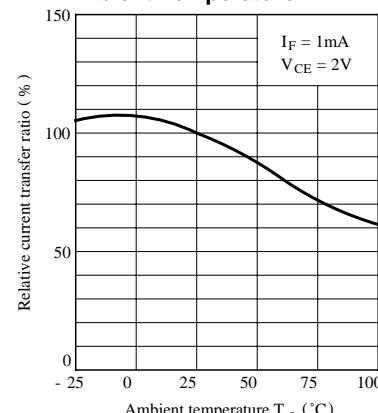
**Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature**



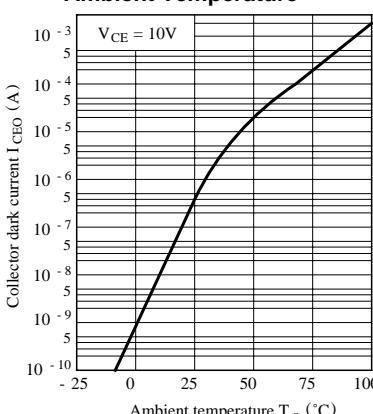
**Fig. 6-a Collector Current vs. Collector-emitter Voltage**

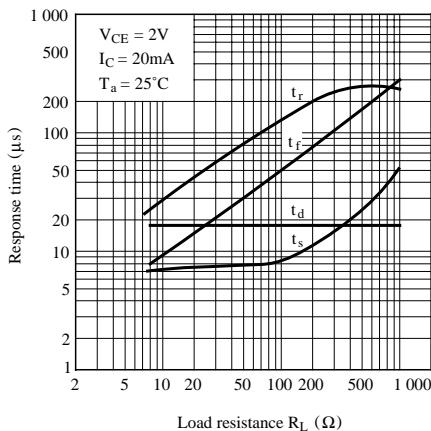
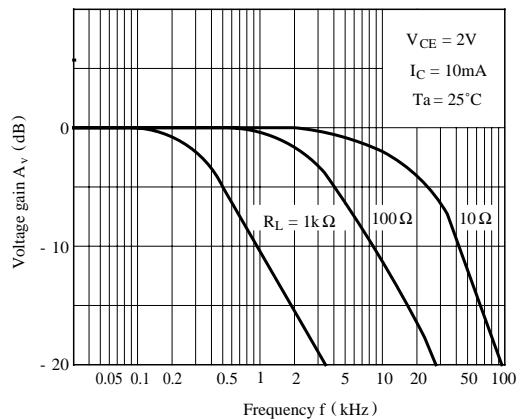
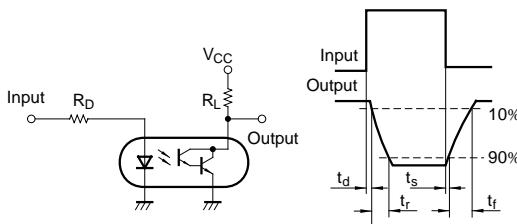
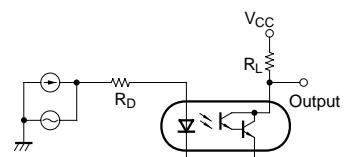


**Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature**



**Fig. 9 Collector Dark Current vs. Ambient Temperature**



**Fig.10 Response Time vs. Load Resistance****Fig.11 Frequency Response****Test Circuit for Response Time****Test Circuit for Frequency Response**

●Please refer to the chapter “Precautions for Use”.